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FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE LIST OF REFERENCES CITED BY APPLICANT (Use several sheets if necessary)	ATTY. DOCKET NO. 60562.00009	SERIAL NO. New Application
	APPLICANT SAKAI et al	
	FILING DATE April 6, 2006	GROUP Art Unit 2811

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NO.	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	AA	2003/0141504	07/31/03	Kuwabara et al			
	AB						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION YES NO PART.		
/A.O.A./	AC	2003-152191	05/23/2003	Japan					
/A.O.A./	AD	2001-102442	04/13/2001	Japan					xx
/A.O.A./	AE	2000-150664	05/30/2000	Japan					xx
/A.O.A./	AF	10-209453	08/07/1998	Japan					xx
/A.O.A./	AG	2004-349702	12/09/2004	Japan					xx
/A.O.A./	AH	07-335735	12/22/1995	Japan					xx
/A.O.A./	AI	05-021465	01/29/1993	Japan					xx

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

/A.O.A./	AJ	Sasaki et al, "Proposal of a Multi-Layer Channel MOSFET: the application of selective etching for Si/SiGe stacked layers," Applied Surface Science, Vol. 234, pp 270-273.
	AK	
	AL	
EXAMINER /Andrew O. Arena/		DATE CONSIDERED 12/22/2008
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